

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|---|------|-----|------|--|--|------------------|----------|
| 1 | BRS | L1 | 5 | (gate near10 film) near5 (high near dielectric) near10 (substrate) near15 (laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:25 | |
| 2 | BRS | L2 | 133 | (high near dielectric) near10 (substrate) near15 (laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:32 | |
| 3 | BRS | L3 | 183 | (high near dielectric) near10 (substrate) near55 (light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:33 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|---|------|-----|------|---|--|------------------|----------|
| 4 | BRS | L4 | 366 | ((high near dielectric) near10 (substrate)) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:34 | |
| 5 | BRS | L5 | 20 | (gate) near15 ((high near dielectric) near10 (substrate)) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:35 | |
| 6 | BRS | L6 | 20 | ((gate) near15 ((high near dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 17:35 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|---|------|-----|------|---|--|----------------------|----------|
| 7 | BRS | L7 | 1 | ((gate) near15 ((high-dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 17:36 | |
| 8 | BRS | L8 | 726 | ((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 17:36 | |
| 9 | BRS | L9 | 80 | ((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 17:36 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|----|------|-----|------|--|--|----------------------|----------|
| 10 | BRS | L10 | 12 | ((gate) near15 ((dielectric) near10 (substrate))) same ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 17:46 | |
| 11 | BRS | L11 | 122 | ((gate) near15 ((dielectric) near10 (substrate))) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 18:03 | |
| 12 | BRS | L12 | 12 | ((dielectric) near10 (substrate)) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (dop\$3) near35 (conduct\$3) near35 (capacitor) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 18:04 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|----|------|-----|------|---|--|----------------------|----------|
| 13 | BRS | L13 | 379 | ((dielectric) near10 (substrate)) and ((light or laser or irradiat\$3 or illuminat\$3 or radiat\$3 or generat\$3)) near35 (conduct\$3) near35 (capacitor) | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 18:10 | |
| 14 | BRS | L14 | 4 | 6747748.pn. or 6632729.pn. | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 18:22 | |
| 15 | BRS | L15 | 2326 | capacitor near insulating near film | USPAT; US-PG PUB; EPO; JPO; DERWE NT; IBM_T DB | 2004/10/2 3 18:30 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|----|------|-----|------|--|--|------------------|----------|
| 16 | BRS | L16 | 617 | (capacitor near insulating near film) near25 (substrate) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:24 | |
| 17 | BRS | L17 | 29 | (high near dielectric) near25 (capacitor near insulating near film) near25 (substrate) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:23 | |
| 18 | BRS | L18 | 2 | (high near dielectric) near25 (capacitor near insulating near film) near25 (dop\$4) near25 (substrate) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:23 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|----|------|-----|------|--|--|------------------|----------|
| 19 | BRS | L19 | 14 | (capacitor near insulating near film) near25 (substrate) near35 (dop\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:24 | |
| 20 | BRS | L20 | 2 | (capacitor near insulating near film) near25 (dopa\$4) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:30 | |
| 21 | BRS | L21 | 83 | (capacitor near insulating near film) near25 (dop\$4) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:30 | |

| | Type | L # | Hits | Search Text | DBs | Time Stamp | Comments |
|----|------|-----|------|---|--|------------------|----------|
| 22 | BRS | L22 | 10 | (dielectric) near15 (capacitor near insulating near film) near25 (dop\$4) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:32 | |
| 23 | BRS | L23 | 11 | (dielectric) near15 (capacitor near insulating near film) near25 (dop\$4 or implant\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:33 | |
| 24 | BRS | L24 | 94 | (capacitor near insulating near film) near25 (dop\$4 or implant\$3) | USPAT; US-PG PUB; EPO; JPO; DERVENT; IBM_T DB | 2004/10/23 18:33 | |